NSN 5961-01-106-1750

Transistor - Page 1 of 1

AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-01-106-1750

Inclosure Material:

Metal

Overall Length:

Between 0.245 inches and 0.275 inches

Overall Diameter:

Between 0.365 inches and 0.385 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.164 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

65.0 breakdown voltage, collector-to-base, emitter open and 35.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown

voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

4.00 amperes source cutoff current

Power Rating Per Characteristic:

40.0 watts small-signal input power, common-collector

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unc

Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0